

 	<h2 style="color: red;">FQB50N06LTM</h2> <p>Hersteller-Teilenummer: FQB50N06LTM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 52.4A D2PAK</p> <p>Datenblätter:  FQB50N06LTM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1415 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB50N06LTM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 60V 52.4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1415 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.75W (Ta), 121W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	52.4A (Tc)
Rds On (Max) @ Id, Vgs	21 mOhm @ 26.2A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	1630pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	5V, 10V
Vgs (Max)	±20V
Verpackung	Original-Reel®








































FQB50N06LTM ist neu im Original, Suche FQB50N06LTM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB50N06LTM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB50N06LTM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB50N06C VB FQB50N06C VB</p>	 <p>FQB50N06M VB FQB50N06M VB</p>	 <p>FQB50N06LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 52.4A D2PAK</p>	 <p>FQB50N06TM Fairchild/ON Semiconductor MOSFET N-CH 60V 50A D2PAK</p>
 <p>FQB50N06TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 50A D2PAK</p>	 <p>FQB50N06TM-NL VB FQB50N06TM-NL VB</p>	 <p>FQB50N03 VB FQB50N03 VB</p>	 <p>FQB5050CFTM Fairchild Fairchild TO-263</p>

heiße Teile

Mehr

 FQB46N15TM	 FQB47P06	 FQB47P06TM	D FQB4N20L	 FQB4N20LTM
 FQB4N20LTM	 FQB4N20TM	D FQB4N20TM	 FQB4N25TM	 FQB4N25TM
 FQB4N20TM	 FQB4N50TM	 FQB4N50TM	 FQB4N60C	 FQB4N80TM
D FQB4N80TM	 FQB4N90TM	 FQB4N90TM	 FQB4P25TM	 FQB4P25TM
 FQB50N03	 FQB50N06	 FQB50N06C	 FQB50N06L	 FQB50N06LTM
 FQB50N06M	 FQB50N06TM	D FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM
 FQB55N06TM	D FQB55N10	 FQB55N10TM	 FQB55N10TM	 FQB5N20L
 FQB5N30TM	 FQB5N30TM	 FQB5N50C	 FQB5N50CF	 FQB5N50CTM
 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM	D FQB5N90TM	 FQB5N90TM
 FQB5P10TM	 FQB5P10TM	 FQB630TM	 FQB630TM	 FQB65N06

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